



# 1N5817 THRU 1N5819

Reverse Voltage - 20 to 40 Volts Forward Current - 1.0 Ampere

## SCHOTTKY BARRIER RECTIFIER

### Features

- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Guardring for overvoltage protection
- ◆ Low power loss, high efficiency
- ◆ High current capability, low forward voltage drop
- ◆ High surge capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ High temperature soldering guaranteed:  
250°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

### Mechanical Data

**Case** : JEDEC DO-41 Molded plastic body

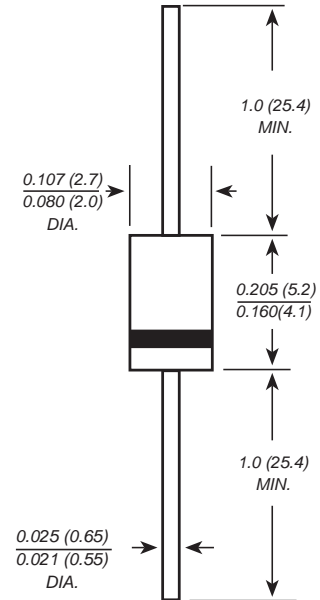
**Terminals** : Solder plated, solderable per MIL-STD-750, Method 2026

**Polarity** : Polarity symbol marking on body

**Mounting Position** : Any

**Weight** : 0.012 ounce, 0.33 grams

DO-41



Dimensions in inches and (millimeters)

### Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	SYMBOLS	1N5817	1N5818	1N5819	UNITS
		MDD 1N5817	MDD 1N5818	MDD 1N5819	
Maximum repetitive peak reverse voltage	$V_{RRM}$	20	30	40	V
Maximum RMS voltage	$V_{RMS}$	14	21	28	V
Maximum DC blocking voltage	$V_{DC}$	20	30	40	V
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_L=90^\circ\text{C}$	$I_{(AV)}$	1.0			A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	25			A
Maximum instantaneous forward voltage at 1.0A	$V_F$	0.450	0.550	0.600	V
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	$I_R$	0.5 10.0			mA
Typical junction capacitance (NOTE 1)	$C_J$	110.0			pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0			$^\circ\text{C}/\text{W}$
Operating junction and storage temperature range	$T_J, T_{STG}$	-65 to +150			$^\circ\text{C}$

**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted



# 1N5817 THRU 1N5819

Reverse Voltage - 20 to 40 Volts Forward Current - 1.0 Ampere

## Ratings And Characteristic Curves

FIG. 1- FORWARD CURRENT DERATING CURVE

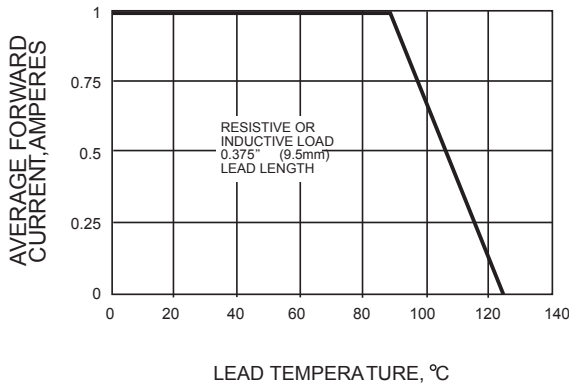


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

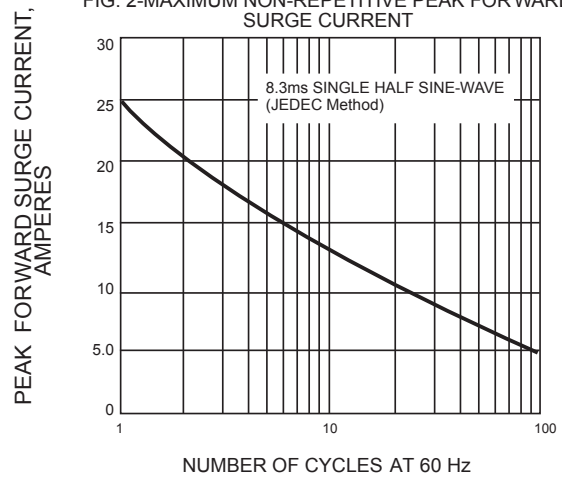


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

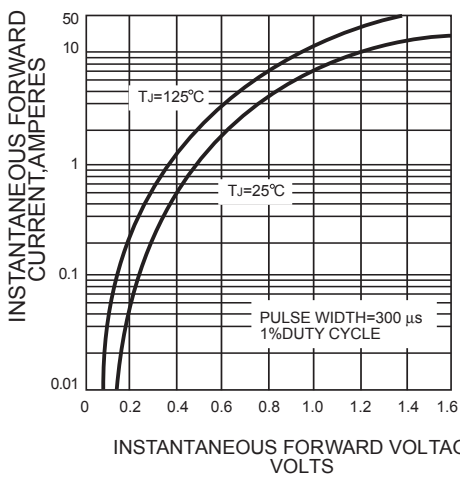


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

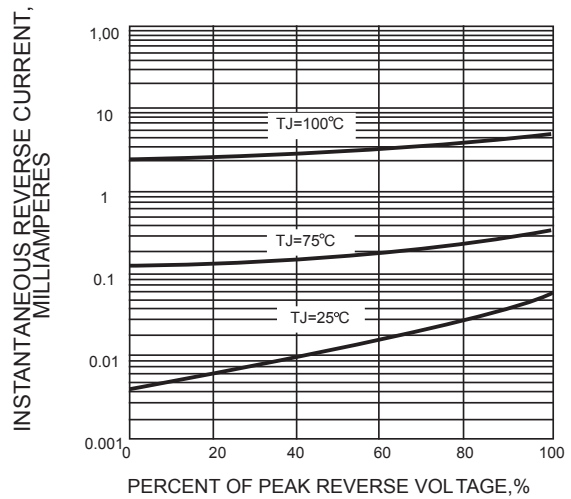


FIG. 5-TYPICAL JUNCTION CAPACITANCE

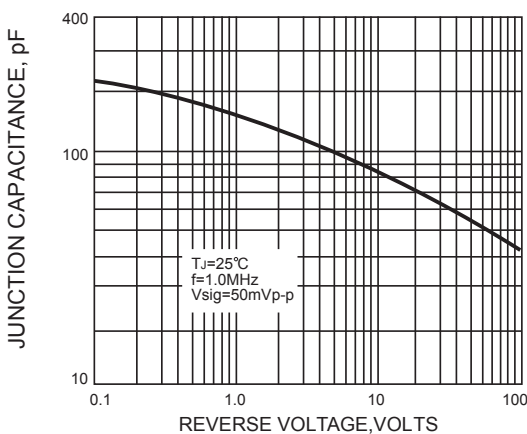
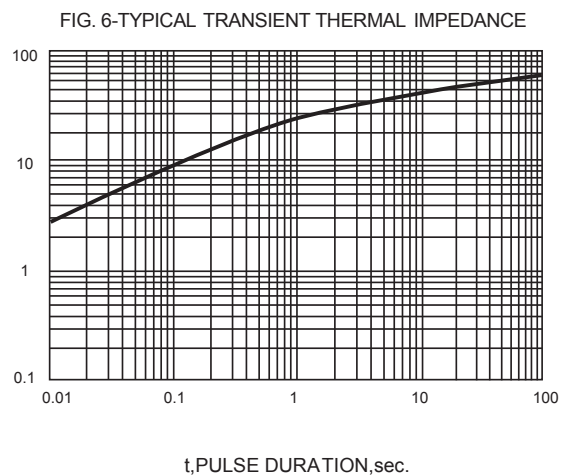


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



The curve above is for reference only.

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [Schottky Diodes & Rectifiers](#) category:*

*Click to view products by [Microdiode Electronics](#) manufacturer:*

Other Similar products are found below :

[MA4E2039](#) [MA4E2508M-1112](#) [MBR10100CT-BP](#) [MBR1545CT](#) [MMBD301M3T5G](#) [GS1JE-TP](#) [RB160M-50TR](#) [BAS 3010S-02LRH E6327](#)  
[BAT 54-02LRH E6327](#) [NSR05F40QNXT5G](#) [NSVR05F40NXT5G](#) [NTE555](#) [JANS1N6640](#) [SB07-03C-TB-H](#) [SBS818-TL-E](#) [SK310-T](#)  
[SK33A-TP](#) [SK34B-TP](#) [SS3003CH-TL-E](#) [PDS3100Q-7](#) [GA01SHT18](#) [CRS10I30A\(TE85L,QM](#) [MA4E2501L-1290](#) [MBRB30H30CT-1G](#)  
[DMJ3940-000](#) [SB007-03C-TB-E](#) [SK32A-TP](#) [SK33B-TP](#) [SK35A-TP](#) [SK38B-LTP](#) [SK38B-TP](#) [NRVBM120LT1G](#) [NTE505](#)  
[NTSB30U100CT-1G](#) [SS0503SH-TL-E](#) [VS-6CWQ10FNHM3](#) [CRG04\(T5L,TEMQ\)](#) [ACDBA1100LR-HF](#) [ACDBA1200-HF](#) [ACDBA2100-HF](#)  
[ACDBA240-HF](#) [ACDBA3100-HF](#) [CDBQC0530L-HF](#) [ACDBA260LR-HF](#) [ACDBA1100-HF](#) [MA4E2502L-1246](#) [10BQ060-M3/5BT](#)  
[NRVB130LSFT1G](#) [CRS08TE85LQM](#) [PMAD1108-LF](#)